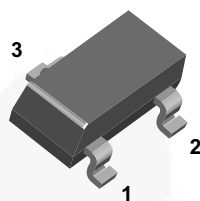


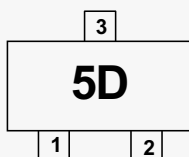


February 2015

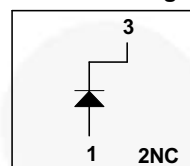
MMBD914 Small Signal Diode



SOT-23



Connection Diagram



Ordering Information

Part Number	Top Mark	Package	Packing Method
MMBD914	5D	SOT-23 3L	Tape and Reel

Absolute Maximum Ratings^{(1), (2)}

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. Values are at $T_A = 25^\circ\text{C}$ unless otherwise noted.

Symbol	Parameter		Value	Unit
V _{RRM}	Maximum Repetitive Reverse Voltage		100	V
I _{F(AV)}	Average Rectified Forward Current		200	mA
I _{FSM}	Non-Repetitive Peak Forward Surge Current	Pulse Width = 1.0 second	1.0	A
		Pulse Width = 1.0 microsecond	2.0	
T _{STG}	Storage Temperature Range		-55 to +150	°C
T _J	Operating Junction Temperature		150	°C

Notes:

1. These ratings are based on a maximum junction temperature of 150°C .
2. These are steady-state limits. Fairchild Semiconductor should be consulted on applications involving pulsed or low-duty-cycle operations.

Thermal Characteristics

Values are at $T_A = 25^\circ\text{C}$ unless otherwise noted.

Symbol	Parameter	Value	Unit
P_D	Power Dissipation	350	mW
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient	357	$^\circ\text{C/W}$

Electrical Characteristics

Values are at $T_A = 25^\circ\text{C}$ unless otherwise noted.

Symbol	Parameter	Conditions	Min.	Max.	Unit
V_R	Breakdown Voltage	$I_R = 5.0 \mu\text{A}$	75		V
		$I_R = 100 \mu\text{A}$	100		
V_F	Forward Voltage	$I_F = 10 \text{ mA}$		1.0	V
I_R	Reverse Current	$V_R = 20 \text{ V}$		25	nA
		$V_R = 20 \text{ V}, T_A = 150^\circ\text{C}$		50	μA
		$V_R = 75 \text{ V}$		5.0	μA
C_T	Total Capacitance	$V_R = 0, f = 1.0 \text{ MHz}$		4.0	pF
t_{rr}	Reverse Recovery Time	$I_F = 10 \text{ mA}, V_R = 6 \text{ V},$ $I_{RR} = 1.0 \text{ mA}, R_L = 100 \Omega$		4.0	ns
V_{FR}	Peak Forward Recovery Voltage	$I_F = 50 \text{ mA}, \text{PEAK SQUARE}$ $\text{WAVE PULSE WIDTH} = 0.1 \mu\text{S}$ $5 \text{ kHz} - 100 \text{ kHz REP RATE}$		2.5	V

Typical Performance Characteristics (Continued)

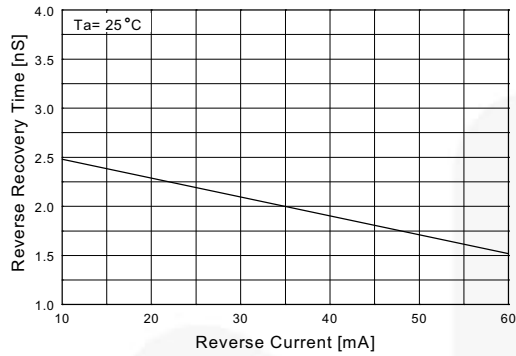


Figure 7. Reverse Recovery Time vs. Reverse Current

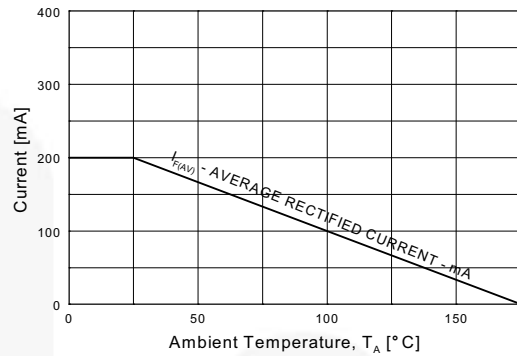


Figure 8. Average Rectified Current($I_{F(AV)}$) vs. Ambient Temperature(T_A)

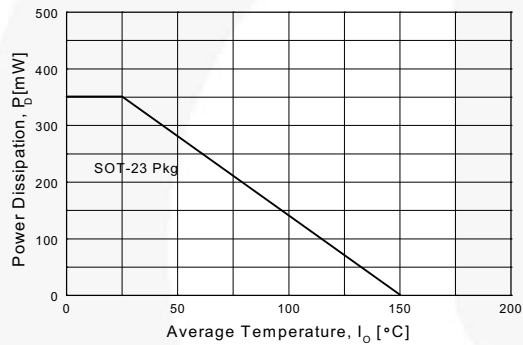


Figure 9. Power Derating Curve

Physical Dimensions

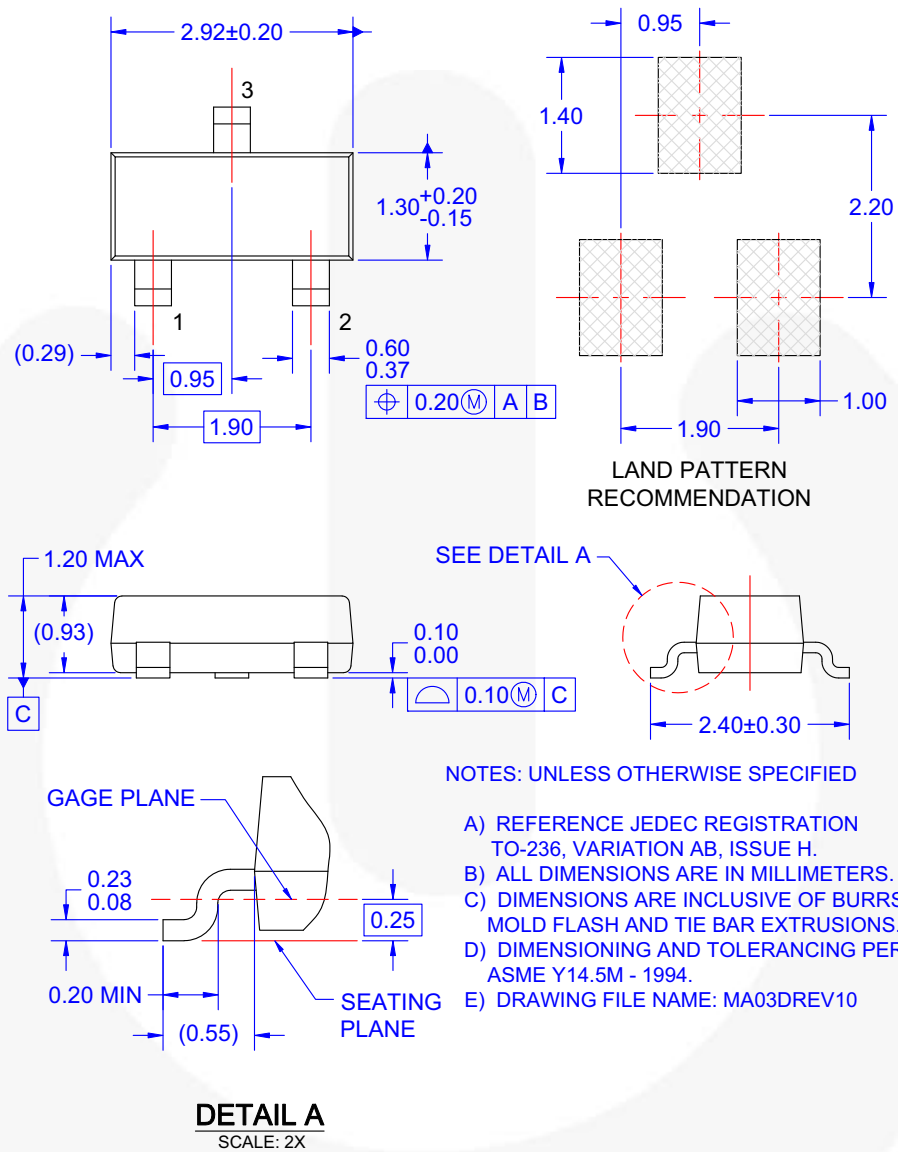


Figure 10. 3-LEAD, SOT23, JEDEC TO-236, LOW PROFILE

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